

Amendments to the Claims

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1-42 Canceled

43. (Currently amended) A light-emissive device comprising:
a light-emissive region;
a first electrode located on a viewing side of the light-emissive region for injecting charge carriers of a first type; and
~~a second electrode located on a non-viewing side of the light-emissive region for injecting charge carriers of a second type~~ comprising a charge injecting layer and a reflectivity-influencing structure, the reflectivity-influencing structure being located on an opposite side of the charge injecting layer from the light-emissive region;
~~and wherein there is a reflectivity-influencing structure located on the non-viewing side of the light-emissive region~~ and including a light absorbent layer comprising an inorganic compound comprising a fluoride or oxide of a metal having a work function of 3.5 eV or less.
44. (Previously presented) A light-emissive device as claimed in claim 43, wherein the first electrode is at least partially light-transmissive.
45. (Currently amended) A light-emissive device as claimed in claim 43, wherein the second electrode further comprises a layer of electrically conductive material and the reflectivity-influencing structure is located on the opposite side of the second electrode from the light-emissive region between the layer of electrically conductive material and the charge injecting layer.

46. (Currently amended) A light-emissive device as claimed in claim 45, wherein the ~~second-electrode~~ charge injecting layer is at least partially light-transmissive.

47. (Currently amended) A light-emissive device as claimed in claim 45, wherein the thickness of the ~~second-electrode~~ charge-injecting layer is less than 30nm.

48. Canceled

49. Canceled

50. (Currently amended) A light-emissive device as claimed in claim ~~49~~ 45, wherein the ~~second-electrode~~ charge injecting layer comprises a fluoride or oxide of a low work function metal.

51. (Currently amended) A light-emissive device as claimed in claim 50, wherein the ~~second-electrode~~ the layer of electrically conductive material comprises aluminium.

52. (Currently amended) A light-emissive device as claimed in claim 43, wherein the reflectivity-influencing structure is effective to absorb light emitted from the light-emissive region that reaches it through the ~~second-electrode~~ charge injecting layer and/or incident light.

53. (Currently amended) A light-emissive device as claimed in claim ~~49~~ 43, wherein the presence of the reflectivity-influencing structure ~~adjacent the second-electrode~~ renders that the second electrode substantially non-reflective to light emitted from the light-emissive region and/or incident light.

54. Canceled

55. (Previously presented) A light-emissive device as claimed in claim 43, wherein the light-emissive region comprises an organic light-emissive material.

56. (Previously presented) A light-emissive device as claimed in claim 43, wherein the light-emissive region comprises a polymer light-emissive material.

57. (Previously presented) A light-emissive device as claimed in claim 43, wherein the light-emissive region comprises a conjugated polymer material.

58. (Previously presented) A light-emissive device as claimed in claim 43, wherein the reflectivity-influencing structure is electrically conductive.